

10th International Conference on Radiation Effects on Semiconductor Materials, Detectors and Devices

Thursday 9 October 2014

3D Detectors (09:00 - 11:00)

time	[id] title	presenter
09:00	[24] 3D Pixels for the AFP Experiment	LOPEZ PAZ, Ivan
09:20	[21] Characterization of 3D and planar Si diodes with different neutron converter materials	Mr MENDICINO, Roberto
09:40	[2] 3D simulations of device electrical characteristics of 3D-Trench electrode detector	Prof. LI, Zheng
10:00	[1] Modeling and simulation of charge collection properties for 3D-Trench electrode detector	LI, Zheng
10:20	[8] Upgrade to the Birmingham Irradiation Facility	Ms PARKER, Kerry